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PTO/SB/21 (09-04)

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Under the Paperwork Reduction Act of 1995, no person	ns are required many	Application Number	ation unless it displays a valid OMB control number. 10/514,429
TRANSMITTA	\L	Filing Date	July 12, 2005
FORM		First Named Inventor	Robert DWILINSKI
(to be used for all correspondence after in	nitial filing)	Art Unit	2879
	_	Examiner Name	Not Yet Assigned
Total Number of Pages in This Submission	on	Attorney Docket Numb	204552033800
ENC	CLOSURES	(Check all that app	ly)
Fee Transmittal Form	Drawing(s)		After Allowance Communication to TC
Fee Attached	Licensing-rel	ated Papers	Appeal Communication to Board of Appeals and Interferences
Amendment/Reply	Petition		Appeal Communication to TC (Appeal Notice, Brief, Reply Brief)
After Final	Petition to Co		Proprietary Information
Affidavits/declaration(s)	Power of Atto	mey, Revocation rrespondence Address	Status Letter
Extension of Time Request	Terminal Dis	claimer	Cther Enclosure(s) (please Identify below):
Express Abandonment Request	Request for	Refund	Form PTO/SB/08a/b Copies of Disclosure Citations (10
x Information Disclosure Statement	CD, Number	of CD(s)	refs) Return Receipt Postcard
Certified Copy of Priority Document(s)	Landso	ape Table on CD	
Reply to Missing Parts/ Incomplete Application	Remarks		
Reply to Missing Parts under 37 CFR 1.52 or 1.53			
	RE OF APPLICA	ANT, ATTORNEY, OR	AGENT
Firm Name MORKISON & FOER	STER LLP		

/Michael Logie/

Date

May 25, 2006

Reg. No.

42,465

10514429 - GAU: 2881 PATENT

Docket No. 204552033800

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: Robert DWILINSKI et al.

Serial No.: 10/514,429

Filing Date: July 12, 2005

For: PHOSPHOR SINGLE CRYSTAL SUBSTRATE AND METHOD FOR

PREPARING THE SAME, AND NITRIDE SEMICONDUCTOR DEVICE

USING THE SAME

Examiner: Not Yet Assigned

Group Art Unit: 2879

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. § 1.97 & 1.98

MS Amendment Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450

Dear Sir:

Pursuant to 37 C.F.R. § 1.97 and § 1.98, Applicants submit for consideration in the above-identified application the documents listed on the attached Form PTO/SB/08a/b. Copies of foreign and non-patent literature documents are also submitted herewith. The Examiner is requested to make these documents of record.

This Supplemental Information Disclosure Statement is submitted before mailing of a first Office Action on the merits; accordingly, no fee or separate requirements are required.

Applicants would appreciate the Examiner initialing and returning the Form PTO/SB/08a/b, indicating that the information has been considered and made of record herein.

05/29/2008

EFS-Web Receipt date: 05/25/2006 10514429 - GAU: 2881

U.S. Serial No. 10/514,429 Atty. Docket No. 204552033800

The information contained in this Supplemental Information Disclosure Statement under 37 C.F.R. § 1.97 and § 1.98 is not to be construed as a representation that: (i) a complete search has been made; (ii) additional information material to the examination of this application does not exist; (iii) the information, protocols, results and the like reported by third parties are accurate or enabling; or (iv) the above information constitutes prior art to the subject invention.

In the unlikely event that the transmittal form is separated from this document and the Patent Office determines that an extension and/or other relief (such as payment of a fee under 37 C.F.R. § 1.17 (p)) is required, Applicants petition for any required relief including extensions of time and authorize the Commissioner to charge the cost of such petitions and/or other fees due in connection with the filing of this document to Deposit Account No. 03-1952 referencing 204552033800.

Dated: May 25, 2006

Respectfully submitted,

Registration No.: 42,465 Morrison & Foerster LLP 1650 Tysons Boulevard

Suite 300

McLean, Virginia 22102 Telephone: 703.760.7770 Facsimile: 703.760.7777

/Michael Logie/

05/29/2008

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ALTERNATIVE TO PTO/SB/08a/b (07-05)

				Complete if Known	
Sui	Substitute for form 1449/PTO			Application Number	10/514,429
10	NFORMATION	ום ו	SCLOSURE	Filing Date	July 12, 2005
	STATEMENT BY APPLICANT (Use as many sheets as necessary)			First Named Inventor	Robert DWILINSKI
Ŭ				Art Unit	2879
				Examiner Name	Not yet assigned
Sheet	1	of	1	Attorney Docket Number	204552033800

U.S. PATENT DOCUMENTS						
-	aminer		Document Number	Publication Date	Name of Patentee or	Pages, Columns, Lines, Where
	aminer ials*	Cite No.1	Number-Kind Code ² (if known)	MM-DD-YYYY	Applicant of Cited Document	Relevant Passages or Relevant Figures Appear
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1		2.	6,046,464	4-4-2000	Schetzina	
1		3.	6,399,500	6-4-2002	Porowski et al.	
T		4.	6,447,604	9-10-2002	Flynn et al.	
Î		5.	6,459,712	10-1-2002	Tanaka et al.	
J	/	6.	6,488,767	12-3-2002	Xu et al.	
A	7M.L	7.	6,686,608	2-3-2004	Takahira	

	FOREIGN PATENT DOCUMENTS								
Examiner Initials*	Cite No.1	Foreign Patant Document Country Code ³ -Number ⁴ -Kind Code ⁵ (# known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T⁴			
/M.L./	8.	JP-2000-327495	11-28-2000			<			
/M.L	9.	JP-2001-85737	3-30-2001		U.S. 6,686,608 listed above	\			

"EXAMINER: Initial II information considered, whether or not citation is in conformance with MPEP 601. Draw line through citation if not in conformance and not considered, include copy of this form with next communication to applicant. Verylaterist unique citation designation number (optional.) "See Mord Codes of See Mord Codes of See

		NON PATENT LITERATURE DOCUMENTS			
Examiner Cite Initials No.1		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, senal, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			
/M.L	10.	YAMANE, Hisanori et al. (1998) "Morphology and Characterization of GaN Single Crystals Grown in a Na Flux," Journal of Crystal Growth 186, pp. 8-12			
П	11.	YAMANE, Hisanon et al. (1998) "Na Flux Growth of GaN Single Crystals," Journal of the Japanese Association for Crystal Growth 25(4), pp. 14-18, with partial English translation			
	12.	WALTEREIT, P. et al. (2000) "Nitride Semiconductors Free of Electrostatic Fields for Efficient White Light-Emitting Diodes." Nature 406, pp. 865-868			
	13.	BRANDT, O. et al. (1999) "Critical Issues for the Growth of High-Quality (AI,Ga) N/GaN and GaN/(In,Ga)N Heterostructures on SIC(0001) by Molecular-Beam Epitaxy," Applied Physics Letters 75(25), pp. 4019-4021			
	14.	Notification from Japanese Patent Office mailed March 14, 2006, directed to JP Application No. 2003-503867, with partial English translation	7		
	15.	Chinese Office Action mailed March 3, 2006, directed to corresponding CN Application No. 02821230.4	7		
V	16.	Office Action mailed March 24, 2006, directed to related U.S. Application No. 10/493,594			
/A/I I	17.	Office Action mailed April 20, 2006, directed to related U.S. Application No. 10/493,747			

"EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Oraw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

'Applicant's unique citation designation number (optional). 'Applicant is to place a check mark here if English language Translation is attached.

	Examiner Signature	/Michael Logie/	Date Considered	05/29/2008
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